

## **IXFB52N90P Datasheet**



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DiGi Electronics Part Number IXFB52N90P-DG

Manufacturer IXYS

Manufacturer Product Number IXFB52N90P

Description MOSFET N-CH 900V 52A PLUS264

Detailed Description N-Channel 900 V 52A (Tc) 1250W (Tc) Through Hole

PLUS264TM



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DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXFB52N90P	IXYS
Series:	Product Status:
HiPerFET™, Polar	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
900 V	52A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	160mOhm @ 26A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
6.5V @ 1mA	308 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	19000 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	1250W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
PLUS264™	TO-264-3, TO-264AA
Base Product Number:	
IXFB52	

## **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



## **OUR CERTIFICATE**

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